

Normally closed DIP4-pin
economic type with
reinforced insulation

PhotoMOS[®]
GU-E 1 Form B
(AQY410EH)



RoHS compliant

FEATURES

1. High cost-performance type of PhotoMOS 1 Form B output

2. Low on-resistance

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



3. Reinforced insulation of 5,000 V

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

4. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. High sensitivity and low on-resistance

Can control max. 0.55 A load current with 5 mA input current.

Low on-resistance of typ. 1Ω (AQY412EH).

6. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Modem
- Telephone equipment
- Electricity, plant equipment
- Sensing equipment

TYPES

Type	I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity	
					Through hole terminal	Surface-mount terminal				
						Tube packing style		Tape and reel packing style		Tube
AC/DC dual use	Reinforced 5,000 V	60 V	550 mA	DIP4-pin	AQY412EH	AQY412EHA	AQY412EHAX	AQY412EHAZ	1 tube contains: 100 pcs. 1 batch contains: 1,000 pcs.	
		350 V	130 mA		AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ		
		400 V	120 mA		AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device. (Ex. the label for product number AQY412EHAX is 412EH.)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Remarks
Input	LED forward current	I _F	50 mA			
	LED reverse voltage	V _R	5 V			
	Peak forward current	I _{FP}	1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW			
Output	Load voltage (peak AC)	V _L	60 V	350 V	400 V	
	Continuous load current	I _L	0.55 A	0.13 A	0.12 A	Peak AC, DC
	Peak load current	I _{peak}	1.5 A	0.4 A	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	500 mW			
Total power dissipation		P _T	550 mW			
I/O isolation voltage		V _{iso}	5,000 V AC			
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F			

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Condition
Input	LED operate (OFF) current	Typical	1.4 mA			I _L =Max.
		Maximum	3.0 mA			
	LED reverse (ON) current	Minimum	0.4 mA			I _L =Max.
Typical		1.3 mA				
	LED dropout voltage	Typical	1.25 (1.14 V at I _F = 5 mA)			I _F = 50 mA
		Maximum	1.5 V			
Output	On resistance	Typical	1Ω	18Ω	26Ω	I _F = 0 mA I _L = Max. Within 1 s on time
		Maximum	2.5Ω	25Ω	35Ω	
	Off state leakage current	Maximum	I _{Leak}	10μA		I _F = 5 mA V _L = Max.
Transfer characteristics	Operate (OFF) time*	Typical	3.0 ms	1.0 ms	0.8 ms	I _F = 0 mA → 5 mA I _L = Max.
		Maximum	10.0 ms	3.0 ms		
	Reverse (ON) time*	Typical	0.2 ms	0.3 ms	0.2 ms	I _F = 5 mA → 0 mA I _L = Max.
		Maximum	1.0 ms			
	I/O capacitance	Typical	C _{iso}	0.8 pF		f = 1MHz V _B = 0 V
Maximum		1.5 pF				
Initial I/O isolation resistance	Minimum	R _{iso}	1,000MΩ		500 V DC	

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	5 to 10	mA

- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.
For more information.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 0 mA; Load voltage: Max.(DC);
Continuous load current: Max.(DC)



GU-E 1 Form B (AQY410EH)

3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



5. LED operate (OFF) current vs. ambient temperature characteristics

Sample: All types;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



6. LED reverse (ON) current vs. ambient temperature characteristics

Sample: All types;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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